

## **INCHANGE SEMICONDUCTOR**

## isc N-Channel Mosfet Transistor

## BUZ330

### • FEATURES

- High speed switching
- Low R<sub>DS(ON)</sub>
- Easy driver for cost effective application
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### DESCRITION

- Automotive power actuator drivers
- Motor controls
- DC-DC converters

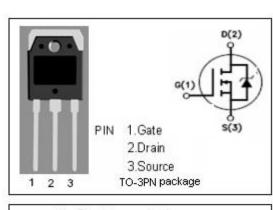
### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

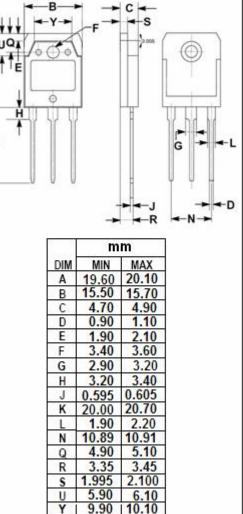
SYMBOL	ARAMETER	VALUE	UNIT				
V <sub>DSS</sub>	Drain-Source Voltage (V <sub>GS</sub> =0)	500	V				
V <sub>GS</sub>	Gate-Source Voltage	±20	V				
ID	Drain Current-continuous@ TC=28℃	9.5	А				
I <sub>DM</sub>	Drain Current-Single Plused	38	А				
P <sub>tot</sub>	Total Dissipation@TC=25℃	125	W				
Tj	Max. Operating Junction Temperature	150	°C				
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C				

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	1.0	°C/W
R <sub>th j-a</sub>	h j-a Thermal Resistance,Junction to Ambient		°C/W

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## ELECTRICAL CHARACTERISTICS

#### Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	МАХ	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> =0.25mA	500			V
$V_{GS(th)}$	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> =1mA	2.1		4.0	V
$V_{\text{SD}}$	Diode Forward On-voltage	I <sub>S</sub> = 19A ;V <sub>GS</sub> = 0			1.4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 6A			0.6	Ω
lgss	Gate-Body Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0			±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =500V; V <sub>GS</sub> = 0			1	μA
Gfs	Forward Transconductance	V <sub>DS</sub> = 25V; I <sub>D</sub> =6A	5			S
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>GS</sub> =10V;			45	
tr	Rise Time	I <sub>D</sub> =3A;			145	
$t_{d(off)}$	Turn-off Delay Time	ີ V <sub>DD</sub> =30V; R <sub>GS</sub> =50 Ω			450	ns
t <sub>f</sub>	Fall Time				150	

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